NSN 5961-01-203-5796

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Inclosure Material:

Metal

Internal Configuration:

Junction contact

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

0.9 base to emitter voltage, dc

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0